

JC06 Rec'd PCT/PTO 19 MAY 2005

Combined Form PTO/SB/08A&B		Complete if Known	
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (use as many sheets as necessary)		Application Number	New application
		Confirmation Number	10/535450
		Filing Date	May 19, 2005
		First Named Inventor	Satoshi TANDA et al.
		Art Unit	4722
		Examiner Name	H. H. H. H.
Sheet	1	of	1
		Attorney Docket Number	052249

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
FH.		US 2002/0117467 A1		08-29-2002	Satoshi TANDA et al.
		US			
		US			
		US			
		US			
		US			
		US			

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)			
FH.		JP	2002-255699		09-11-2002	Komatsu Ltd.	Abstract

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation <sup>6</sup>
FH.		Satoshi TANDA et al.; "A Möbius strip of single crystals", Nature, Vol. 417, pp. 397-398, May 23, 2002. Cited in the enclosed international search report.	Yes
FH.		Satoshi TANDA et al.; "Topological Bushitsu, Solid state physics", Vol. 37, No. 8, pp.17-26. August 15, 2002. Cited in the enclosed international search report.	No.

Examiner Signature	<i>John H. H.</i>	Date Considered	5/11/2007
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